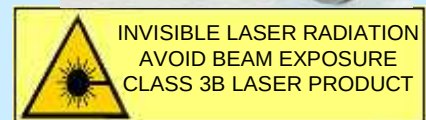


Single mode & polarization VCSEL 850nm, TO46, 0.7mW

- ◆ Single-mode & single-polarization
- ◆ Ideal circular gaussian beam
- ◆ Stable Polarization
- ◆ Built-in ESD protection structure
- ◆ High reliability, 10 years @ 85°C



Preliminary

ELECTRO-OPTICAL CHARACTERISTICS

T=20°C unless otherwise stated

PARAMETER	SYMBOL	UNITS	MIN	TYP	MAX	TEST CONDITIONS
Emission wavelength	λ_R	nm	845	855	860	$P_{op}=0.7\text{ mW}$
Threshold current	I_{TH}	mA	0.2		1.0	
Laser current	I_{OP}	mA	1.2		3.0	$P_{opt}=0.7\text{ mW}$
Laser voltage	U_{OP}	V			2.6	$P_{opt}=0.7\text{ mW}$
Slope efficiency	η_S	W/A	0.4		0.9	
Output power	P_{opt}	mW	0.7			$I_{OP}=3.0\text{ mA}$
Differential series resistance	R_S	Ω	150		350	$P_{opt}=0.7\text{ mW}$
Thermal resistance (VCSEL chip)	$R_{thermal}$	K/mW	3		5	
Beam divergence	θ	°	10		20	$P_{opt}=0.7\text{ mW}$, FWHM
Side mode suppression ratio	SMSR	dB	10			$P_{opt}=0.7\text{ mW}$
ESD damage threshold		V	2000			human body model
Wavelength tuning over temperature		nm/K		0.06		

NOTE: Polarization control by optical design

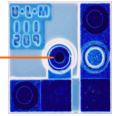
ABSOLUTE MAXIMUM RATINGS

Storage temperature	-40 .. 125°C
Operating temperature	-40 .. 85°C
Electrical power dissipation	7.5 mW
Continuous forward laser current	3.1 mA
Laser reverse voltage	8V
Soldering temperature	330°C

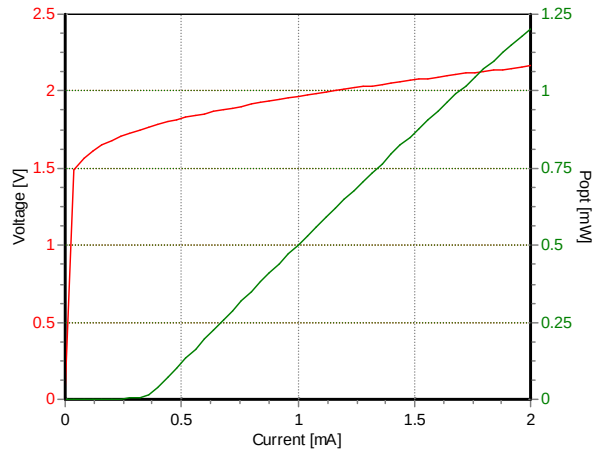
NOTICE: Stresses greater than those listed under „Absolute Maximum Ratings“ may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated for extended periods of time may effect device reliability.



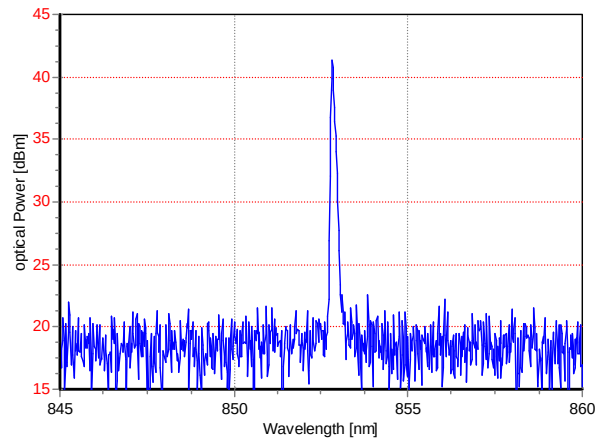
ATTENTION: Electrostatic Sensitive Devices
Observe Precautions for Handling



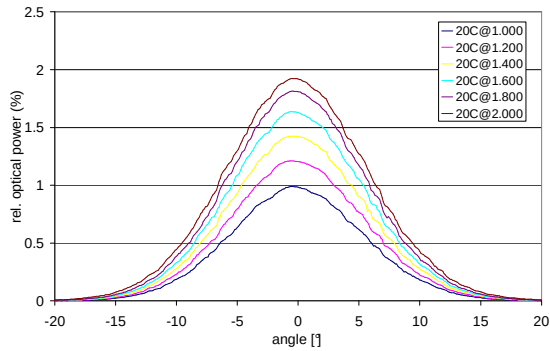
Electro-optical characteristics



Spectral Characteristics



Farfield



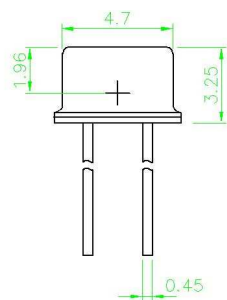
Typ	ULM850-PM-PL-S46XZP
Descripn.	850nm SM VCSEL TO46
Cap	Cap without glass window

Typ	ULM850-PM-PL-S46FZP
Cap	Flat window cap



Package / pin layout

without glass window



flat glass window

